

14-Bit Binary Counter and **Oscillator**

MC14060B

The MC14060B is a 14-stage binary ripple counter with an on-chip oscillator buffer. The oscillator configuration allows design of either RC or crystal oscillator circuits. Also included on the chip is a reset function which places all outputs into the zero state and disables the oscillator. A negative transition on Clock will advance the counter to the next state. Schmitt trigger action on the input line permits very slow input rise and fall times. Applications include time delay circuits, counter controls, and frequency dividing circuits.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, Vin and V_{out} should be constrained to the range $V_{SS} \le (V_{in} \text{ or } V_{out}) \le V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either VSS or VDD). Unused outputs must be left open.

Features

- Fully Static Operation
- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 V to 18 V
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- Buffered Outputs Available from Stages 4 Through 10 and 12 Through 14
- Common Reset Line
- Pin-for-Pin Replacement for CD4060B
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	-0.5 to V _{DD} +0.5	٧
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P _D	Power Dissipation, per Package (Note 1)	500	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8 Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C from 65°C To 125°C.

1

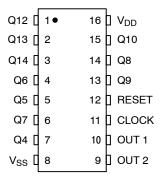


SOIC-16 **D SUFFIX CASE 751B**

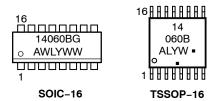


DT SUFFIX CASE 948F

PIN ASSIGNMENT



MARKING DIAGRAMS



= Assembly Location

WL, L = Wafer Lot = Year WW. W = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Table 1. Truth Table

Clock	Reset	Output State
H ~	LLH	No Change Advance to Next State All Outputs are Low

X = Don't Care

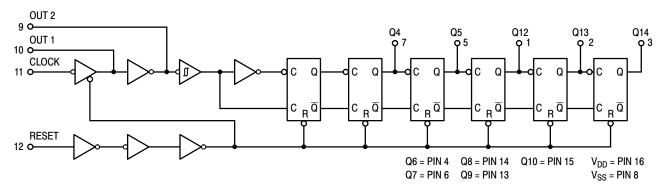


Figure 1. Logic Diagram

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14060BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14060BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
MC14060BDTR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC14060B

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			-55	5°C	25°C 1			125	5°C	
Symbol	Characteristic	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
V _{OL}	Output Voltage "0" Level $V_{in} = V_{DD}$ or 0	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	V
V _{OH}	V _{in} = 0 or V _{DD} "1" Level	5.0 10 15	4.95 9.95 14.95	1 1 1	4.95 9.95 14.95	5.0 10 15	1 1 1	4.95 9.95 14.95	1 1 1	V
V _{IL}	Input Voltage "0" Level (V _O = 4.5 or 0.5 V) (V _O = 9.0 or 1.0 V) (V _O = 13.5 or 1.5 V)	5.0 10 15	- - -	1.5 3.0 4.0	- - -	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	٧
V _{IH}	$(V_O = 0.5 \text{ or } 4.5 \text{ V})$ "1" Level $(V_O = 1.0 \text{ or } 9.0 \text{ V})$ $(V_O = 1.5 \text{ or } 13.5 \text{ V})$	5.0 10 15	3.5 7.0 11.0	1 1 1	3.5 7.0 11.0	2.75 5.50 8.25	1 1 1	3.5 7.0 11.0	1 1 1	V
V _{IL}		5.0 10 15	- - -	1.0 2.0 2.5	- - -	2.25 4.50 6.75	1.0 2.0 2.5	- - -	1.0 2.0 2.5	Vdc
V _{IH}	$(V_O = 0.5 \text{ Vdc})$ "1" Level $(V_O = 1.0 \text{ Vdc})$ $(V_O = 1.5 \text{ Vdc})$	5.0 10 15	4.0 8.0 12.5		4.0 8.0 12.5	2.75 5.50 8.25		4.0 8.0 12.5		Vdc
I _{OH}	Output Drive Current (V _{OH} = 2.5 V) (Except Source (V _{OH} = 4.6 V) Pins 9 and 10) (V _{OH} = 9.5 V) (V _{OH} = 13.5 V)	5.0 5.0 10 15	-3.0 -0.64 -1.6 - 4.2	- - -	-2.4 -0.51 -1.3 -3.4	-4.2 -0.88 -2.25 -8.8	- - -	- 1.7 - 0.36 - 0.9 - 2.4	- - -	mA
I _{OL}	$(V_{OL} = 0.4 \text{ V})$ Sink $(V_{OL} = 0.5 \text{ V})$ $(V_{OL} = 1.5 \text{ V})$	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mA
l _{in}	Input Current	15	_	±0.1	_	±0.00001	±0.1	_	±1.0	μΑ
C _{in}	Input Capacitance (V _{in} = 0)	-	-	-	_	5.0	7.5	-	-	pF
I _{DD}	Quiescent Current (Per Package)	5.0 10 15	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μΑ
I _T	Total Supply Current (Notes 3, 4) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching)	5.0 10 15	$\begin{aligned} I_T &= (0.25 \ \mu\text{A/kHz}) \ \text{f} + I_{DD} \\ I_T &= (0.54 \ \mu\text{A/kHz}) \ \text{f} + I_{DD} \\ I_T &= (0.85 \ \mu\text{A/kHz}) \ \text{f} + I_{DD} \end{aligned}$						μА	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

<sup>Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise in performance may not be indicated by the Electrical Characteristics if operated under different conditions.
2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF: I_T(C_L) = I_T(50 pF) + (C_L – 50) Vfk where: I_T is in μA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.002.</sup>

SWITCHING CHARACTERISTICS ($C_L = 50 \ pF, \ T_A = 25^{\circ}C$)

Symbol	Characteristic	V _{DD} Vdc	Min	Typ (Note 5)	Max	Unit
t _{TLH}	Output Rise Time (Counter Outputs)	5.0 10 15	- - -	40 25 20	200 100 80	ns
t _{THL}	Output Fall Time (Counter Outputs)	5.0 10 15	- - -	50 30 20	200 100 80	ns
t _{PLH} t _{PHL}	Propagation Delay Time Clock to Q4	5.0 10 15	- - -	415 175 125	740 300 200	ns
	Clock to Q14	5.0 10 15	- - -	1.5 0.7 0.4	2.7 1.3 1.0	μs
t _{wH}	Clock Pulse Width	5.0 10 15	100 40 30	65 30 20	- - -	ns
f_{Φ}	Clock Pulse Frequency	5.0 10 15	- - -	5 14 17	3.5 8 12	MHz
t _{TLH} t _{THL}	Clock Rise and Fall Time	5.0 10 15	No Limit			ns
t _w	Reset Pulse Width	5.0 10 15	120 60 40	40 15 10	- - -	ns
t _{PHL}	Propagation Delay Time Reset to On	5.0 10 15	- - -	170 80 60	350 160 100	ns

^{5.} Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

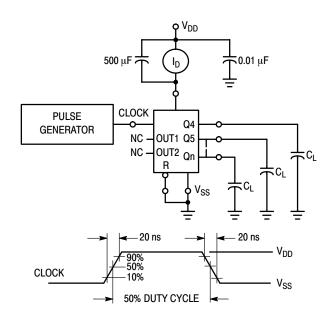


Figure 1. Power Dissipation Test Circuit and Waveform

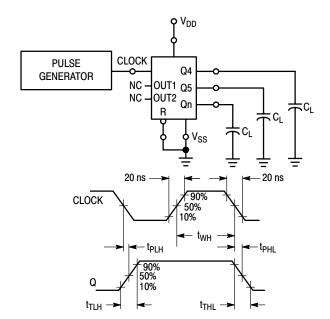
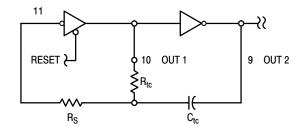


Figure 2. Switching Time Test Circuit and Waveforms

MC14060B



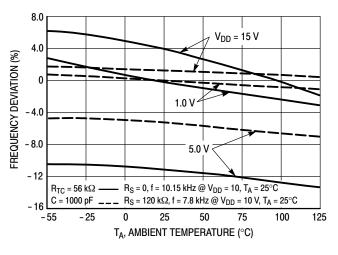
$$f \approx \frac{I}{2.3 \, R_{tc} C_{tc}}$$
if 1 kHz \le f \le 100 kHz

if 1 kHz \leq f \leq 100 kHz and 2R_{tc} < R_S < 10R_{tc} (f in Hz, R in ohms, C in farads)

The formula may vary for other frequencies. Recommended maximum value for the resistors in 1 $M\Omega.$

Figure 3. Oscillator Circuit Using RC Configuration

TYPICAL RC OSCILLATOR CHARACTERISTICS



100 V_{DD} = 10 V 50 f, OSCILLATOR FREQUENCY (kHz) f AS A FUNCTION 20 OF R_{TC} 10 (C = 1000 pF) $(R_S \approx 2R_{TC})$ 5 f AS A FUNCTION 2 OF C $(R_{TC} = 56 \text{ k}\Omega)$ $(R_S = 120 \text{ k})$ 0.5 0.2 1.0 k 100 k 10 k 1.0 M R_{TC}, RESISTANCE (OHMS) 0.0001 0.1 0.001 0.01 C, CAPACITANCE (µF)

Figure 4. RC Oscillator Stability

Figure 5. RC Oscillator Frequency as a Function of R_{TC} and C

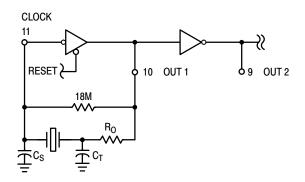


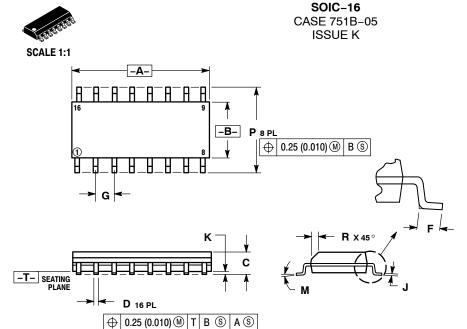
Figure 6. Typical Crystal Oscillator Circuit

Table 2.	Typical Dat	a for Crys	stai Usci	llator	Circuit	

Characteristic	500 kHz Circuit	32 kHz Circuit	Unit
Crystal Characteristics Resonant Frequency Equivalent Resistance, R _S	500 1.0	32 6.2	kHz kΩ
External Resistor/Capacitor Values RO CT CS	47 82 20	750 82 20	kΩ pF pF
Frequency Stability Frequency Changes as a Function of V _{DD} (T _A = 25°C) V _{DD} Change from 5.0 V to 10 V V _{DD} Change from 10 V to 15 V Frequency Change as a Function of Temperature (V _{DD} = 10 V) T _A Change from - 55°C to +25°C Complete Oscillator (Note 6)	+6.0 +2.0 +100	+2.0 +2.0 +120	ppm ppm
T _A Change from + 25°C to + 125°C Complete Oscillator (Note 6)	-160	–560	ppm

6. Complete oscillator includes crystal, capacitors, and resistors.

MECHANICAL CASE OUTLINE



DATE 29 DEC 2006

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- THE NOTION AND TOLETANOING FER ANSI'Y 14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- PHOI HUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR PROTRUSION

 SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D

 DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
C	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

2. 3.	COLLECTOR BASE EMITTER NO CONNECTION EMITTER BASE COLLECTOR COLLECTOR BASE EMITTER NO CONNECTION EMITTER BASE	2. 3. 4. 5. 6. 7. 8. 9. 10.	CATHODE ANODE NO CONNECTION CATHODE CATHODE NO CONNECTION ANODE CATHODE CATHODE ANODE NO CONNECTION ANODE CATHODE CATHODE CATHODE CATHODE CATHODE CATHODE	2. 3. 4. 5. 6. 7. 8. 9. 10.	COLLECTOR, DYE #1 BASE, #1 EMITTER, #1 COLLECTOR, #1 COLLECTOR, #2 BASE, #2 EMITTER, #2 COLLECTOR, #2 COLLECTOR, #2 COLLECTOR, #3	STYLE 4: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13.	COLLECTOR, #1 COLLECTOR, #2 COLLECTOR, #3 COLLECTOR, #3 COLLECTOR, #4 COLLECTOR, #4 BASE, #4 EMITTER, #4 BASE, #3		
14.	COLLECTOR		NO CONNECTION	14.		14.		SOLDERING	FOOTPRINT
15.	EMITTER		ANODE	15.		15.		8)	(
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1	6.4	
STYLE 5: PIN 1. 2. 3. 4. 5. 6. 7. 8.	DRAIN, DYE #1 DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #4 DRAIN, #4 GATE, #4	STYLE 6: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	CATHODE	STYLE 7: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9.	SOURCE N-CH COMMON DRAIN (OUTPU' GATE P-CH COMMON DRAIN (OUTPU' COMMON DRAIN (OUTPU' COMMON DRAIN (OUTPU' SOURCE P-CH SOURCE P-CH	T) T) T)	1 0.	6X 1 1 1 1 1 1 1 1 1 1	16
10.	SOURCE, #4	10.	ANODE	10.	COMMON DRAIN (OUTPUT	T)			
11.	GATE, #3	11.		11.	COMMON DRAIN (OUTPUT				
12.	SOURCE, #3	12.	ANODE	12.	COMMON DRAIN (OUTPUT				1.07
13.	GATE, #2	13.	ANODE	13.	GATE N-CH				
14.	SOURCE, #2	14.		14.	COMMON DRAIN (OUTPUT				↓ PITCH
15.	GATE, #1	15.	ANODE	15.	COMMON DRAIN (OUTPUT	T)			+
16.	SOURCE, #1	16.	ANODE	16.	SOURCE N-CH			8	9 + - + + + + + + + + + + + + + + + + +

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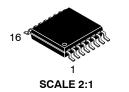
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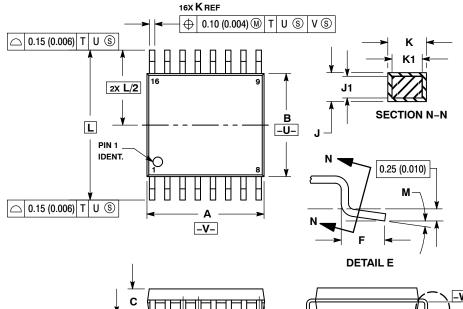
-T- SEATING PLANE





TSSOP-16 CASE 948F-01 ISSUE B

DATE 19 OCT 2006



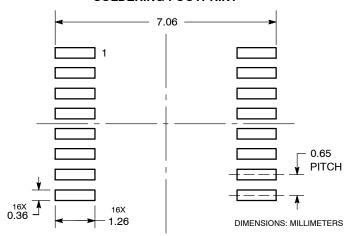
NOTES

- JIES:
 DIMENSIONING AND TOLERANCING PER
 ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD
 FLASH. PROTRUSIONS OR GATE BURRS.
 MOLD EL ROLL OF GATE BURDS SUAL NO.
- MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
Н	0.18	0.28	0.007	0.011	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
Κ	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
Г	6.40		0.252 BSC		
М	0 °	8°	0 °	8 °	

SOLDERING FOOTPRINT

G



GENERIC MARKING DIAGRAM*

168888888 XXXX XXXX **ALYW** 188888888

XXXX = Specific Device Code Α = Assembly Location

= Wafer Lot L Υ = Year W = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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